



On the U–Cu–Al and U–Cu–Ga systems at 600 °C

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ABSTRACT

The phase relations in the U–Cu–Al and U–Cu–Ga systems have been studied at 600 °C in concentration region of 0–45/75 at.% Al and 0–40/75 at.% Ga, respectively. X-ray diffraction techniques, optical microscopy and scanning electronic microscopy, complemented with energy dispersive X-ray spectroscopy (EDS), were used to identify the phases and characterize their crystal structures and compositions. Five new ternary phases have been identified for the first time: $\text{UCu}_{6+x}\text{Al}_{5-x}$ ($x \sim 0\text{--}0.2$) (TbCu_{6,4}Al_{4,6} structure type), $\text{UCu}_{6+x}\text{Al}_{5-x}$ ($x \sim 0.38\text{--}0.68$) (BaCd₁₁ structure type), $\text{U}_{2-\varepsilon}(\text{Cu}_{7+x}\text{Ga}_{10-x})_{1+\delta}$ ($\varepsilon \sim 0.5$, $\delta \sim 0.03$, $x \sim 0.5\text{--}1$) (related to Th₂Ni₁₇ structure type), $\text{UCu}_{5+x}\text{Ga}_{1-x}$ ($x \sim 0\text{--}0.7$) (CeCu₆ structure type) and $\text{U}_{14}\text{Cu}_{44+x}\text{Ga}_{7-x}$ ($x \sim 0.5\text{--}2.5$) (related to Gd₁₄Ag₅₁ structure type). The crystal structure of the $\text{UCu}_{5+x}\text{Ga}_{1-x}$ and $\text{U}_{14}\text{Cu}_{44+x}\text{Ga}_{7-x}$ intermetallics has been determined from X-ray single crystal counter data.

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1. Introduction

The production of new materials with pre-defined physical and chemical properties is one of the most important aims of modern technology. Uranium based compounds and alloys occupy an important place among them. Moreover, due to the unusual behaviour of many uranium based intermetallic phases, they are also interesting from the scientific point of view. Those compounds exhibit a great variety of physical phenomena, such as long range exotic magnetic order, spin-glass behaviour, Kondo effects, heavy fermion ground state, unconventional superconductivity, intermediate valence state etc. It is considered that these electronic features are mainly related to the degree of hybridization between the 5f and s, p and d orbitals of neighbour atoms. The best way for finding and studying the conditions of the formation of ternary compounds is the systematic oriented investigation of the phase diagrams, which reflects the phase composition of the alloys and gives information on the conditions of the compounds formation (stability of the compounds, transformation of the structures versus composition and temperature).

Many uranium-based alloy systems and intermetallic compounds have been already studied. However, a big lack of data on some uranium – d- and p- metals interactions still occur among them. For example, summarized data on interaction among the components in

the U – d – metal – {Al, Ga, In} systems are displayed in the Table 1. Up to our best knowledge, the systematic oriented investigations were mainly performed on the systems with 4d metals, and only some specific compositions were studied in the other ones. In total, twelve isothermal sections were constructed and the existence of 132 ternary phases has been described in the literature [1–5] and references herein. We have stopped our attention on the U–Cu–Al and U–Cu–Ga systems. Herein, we present isothermal sections of above mentioned systems at 600 °C and crystal structure determination of the new ternary phases.

2. Literature data

2.1. Binary systems

A brief summary of the literature data focussing on phase equilibrium of the binary U–Cu–(Al, Ga) subsystems is presented here.

The U–Al system was studied by Gordon and Kaufmann [6]. Three binary compounds exist in this system: UAl_4 (own type), UAl_3 (AuCu₃-type) and UAl_2 (MgCu₂-type). The U–Ga phase diagram was constructed by Buschow [7]; at least three binary compounds have been identified in above mentioned system: UGa_3 (AuCu₃-type), UGa_2 (AlB₂-type) and U_3Ga_5 (Pu₃Pd₅-type). Interaction between the components in the U–Cu system [8] is characterized by the formation of only one compound, UCu_5 , with AuBu_5 structure type.

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Table 1
Summarized data on the ternary U–M–(Al, Ga, In) systems.

Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn
□ (1)	□ (2)	□ (3)	■ (2) □ (1)	■ (7) ■ (7)	■ (7) ■ (10) ■ (2)	■ (5) ■ (8) ■ (4)	□ (7) □ (4) ■ (2)	
Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd
■ (0)	□ (2)	■ (3)		□ (3) □ (3) □ (1)	□ (2) □ (5) □ (3)	□ (2) □ (5) □ (3)		
Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg
	□ (2)	□ (2)		□ (1) □ (1)	□ (3) □ (3) □ (2)	□ (1) □ (3) □ (3)	□ (3) □ (2) □ (1)	

Cu – M.

□ (7) – R–M–Al system.

□ (4) – R–M–Ga system.

■ (2) – R–M–In system.

Phase equilibrium is established in the whole concentration region or in a part of it (■), only separate alloys have been investigated (□). Lack of a symbol means the system has not yet been investigated. (N) – Number of ternary compounds.

Interaction between the components in the Cu–Al [9,10] and Cu–Ga [11,12] system has a complex character. Fourteen (CuAl₂, rt– and ht–CuAl, rt– and ht–Cu₄Al₃, ht1– and ht2–Cu₃Al₂, Cu₃₃Al₁₇, rt– and ht–Cu₉Al₄, Cu₇Al₃, rt– and ht–Cu₃Al, Cu₄Al) and eight (CuGa₂, Cu₃Ga₂, Cu₂Ga, rt– and ht–Cu₉Ga₄, rt–, ht1– and ht2–Cu₄Ga) intermediate phases have been established, respectively. More detailed information on the composition and structure of these phases can be found in supplementary data (Table S1–S2).

2.2. Ternary systems

There is no data in the literature on the investigation of the phase diagram of the U–Cu–Al and U–Cu–Ga systems. However, the crystal structure and properties of certain ternary U–Cu–{Al, Ga} compounds were widely studied [13–19] and references herein. Due to the large number of publications we referred only papers where certain phases were reported for first time. Seven ternary phases are known from the U–Cu–Al system: UCuAl₂ (TiAl₃-type) [14], U₃Cu₂Al (MgZn₂-type) [14], U₂Cu₉Al (MgZn₂-type) [15], UCu_{3+x}Al_{2-x} ($x \sim 0-0.5$) (CaCu₅-type) [15,16], UCu₅Al (YbMo₂Al₄-type) [17], U₂Cu_{7+x}Al_{10-x} (Th₂Zn₁₇-type) ($x \sim 0-5$) [18,19] and UCu_{4+x}Al_{8-x} ($x \sim 0-2$) (ThMn₁₂-type) [18,20]. The existence of five ternary gallides have been described up to now: U₂Cu_{7+x}Ga_{10-x} ($x \sim 0.7-5$) (Th₂Zn₁₇-type) [19,21], UCu_{1+x}Ga_{3-x} ($x \sim 0.33-0.5$) (BaAl₄-type) [22], UCu_{3+x}Ga_{2-x} ($x \sim 0-0.8$) (CaCu₅-type) [23,24], UCuGa (CaIn₂-type or LiGaGe-type) [25,26], UCu_xGa_{2-x} ($x \sim 0-0.56$) (Lu₂CoGa₃-type at $x = 0.5$ and AlB₂-type at $x \neq 0.5$) [26,27].

3. Experimental details

Metals with nominal purities 99.95 wt.% (uranium ingots), 99.99 wt.% (copper rod and plate), 99.95 wt.% (aluminium spheres) and 99.995 wt.% (gallium pieces) were used as a starting materials. A total of 64 (U–Cu–Al system) and 78 (U–Cu–Ga system) binary and ternary samples with a total weight 0.5–1.0 g were prepared by arc-melting the elements under argon atmosphere. The products were re-melted at least three times in order to ensure homogeneity. Finally, alloys were defragmented into small pieces, sealed in evacuated quartz tubes under vacuum (10^{-5} Torr) and annealed at 600 °C for one month. After the heat treatments, the samples were quenched, by submerging the quartz tubes in cold water, and analysed.

The polycrystalline products were crushed, powdered with agate mortar and examined by X-ray diffraction. X-ray phase and structural analysis were performed using a PANalytical X'Pert Pro diffractometer (Cu K α -radiation). The scans were taken in the $\theta/2\theta$ mode with the following parameters: 2θ region 15–120°; step scan 0.03°; counting time per step 2–20 s. The theoretical powder patterns were calculated with the help of the PowderCell program [28]. The lattice parameters were obtained by least-squares fitting using the Latcon program [29]. The FullProf [30] program was used for Rietveld refinements. Pseudo-Voigt profile shape function was used. The background was refined with a polynomial function. Results of these fittings of selected phases are given in supplementary data (Table S3).

Single crystals suitable for X-ray diffraction measurements were selected from the crushed samples obtained by slowly cooling from 1000 °C to room temperature within 10 h. The single crystal intensity data were collected at room temperature using a four-circle Enraf–Nonius Mach III diffractometer with graphite monochromatized Mo K α -radiation and a scintillation counter with pulse height discrimination. Scans were taken in the $\omega/2\theta$ mode. Empirical absorption corrections were applied on the basis of Ψ -scan data. The crystal structures were refined using Shelxl-97 [31] (full-matrix least-squares on F^2). The unit cell parameters were obtained by least-squares refinement of the 2θ values of 25 intense and well-centred reflections from various parts of the reciprocal space ($15^\circ < 2\theta < 35^\circ$).

The microstructure of the samples was first studied on polished and etched surfaces, by using an optical microscope Olympus OM150. Selected samples were then observed by electron microscopy, by using a JEOL JSM-T330A scanning electron microscope (SEM) operated at 25 kV. The composition phases were also analysed by semi-quantitative energy dispersive X-ray spectroscopy (EDS). At least three valid EDS point analyses were made for each phase in order to guarantee a good analysis of their compositions. These analyses were carried out with a spatial resolution of $\sim 2 \mu\text{m}$ and a collection time of 200 s. The AnalySIS 3.0 (from Soft Imaging System GmbH) and Quest SpectraPlus (from Termo Noran) softwares were used.

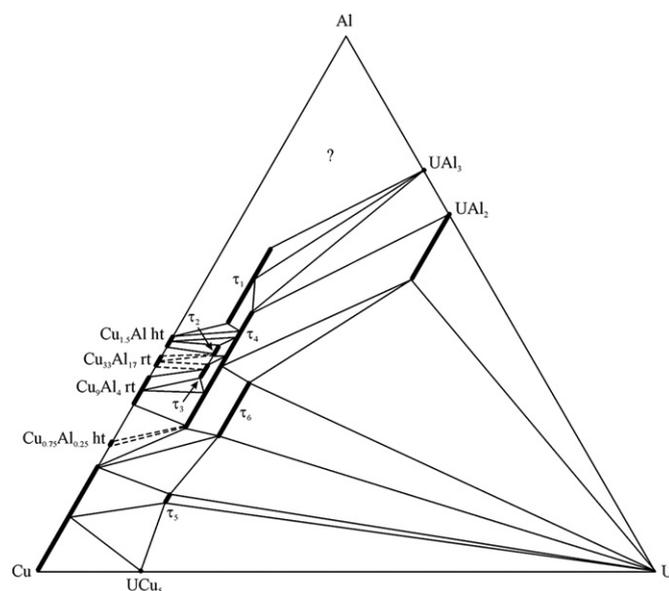


Fig. 1. Isothermal section of the U–Cu–Al system at 600 °C. Ternary phases: (τ_1) UCu_{4+x}Al_{8-x} ($0 \leq x \leq 2$); (τ_2) UCu_{6+x}Al_{5-x} ($0 \leq x \leq 0.2$); (τ_3) UCu_{6+x}Al_{5-x} ($0.38 \leq x \leq 0.68$); (τ_4) U₂Cu_{7+x}Al_{10-x} ($0.6 \leq x \leq 5$); (τ_5) UCu_{5+x}Al_{1-x} ($0 \leq x \leq 0.18$); (τ_6) UCu_{3+x}Al_{2-x} ($0 \leq x \leq 0.5$).

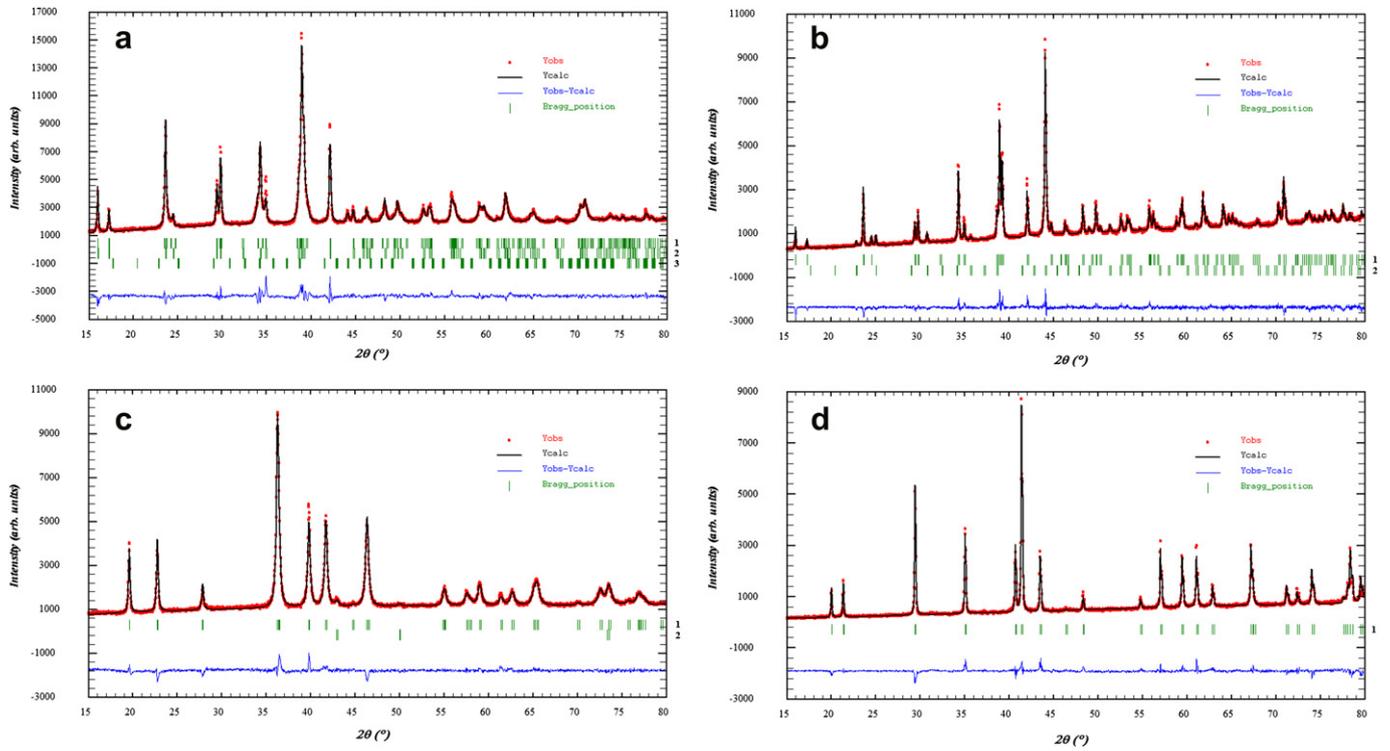


Fig. 2. X-ray diffraction patterns of selected U–Cu–Al alloys: (a) $U_8Cu_{52}Al_{40}$ (1 – τ_2 , 2 – τ_3 , 3 – $Cu_{33}Al_{17}$ rt); (b) $U_5Cu_{61}Al_{34}$ (1 – τ_3 , 2 – Cu_9Al_4 rt); (c) $U_{14}Cu_{74}Al_{12}$ (1 – τ_5 , 2 – Cu); (d) $U_{17}Cu_{55}Al_{28}$ (1 – τ_6).

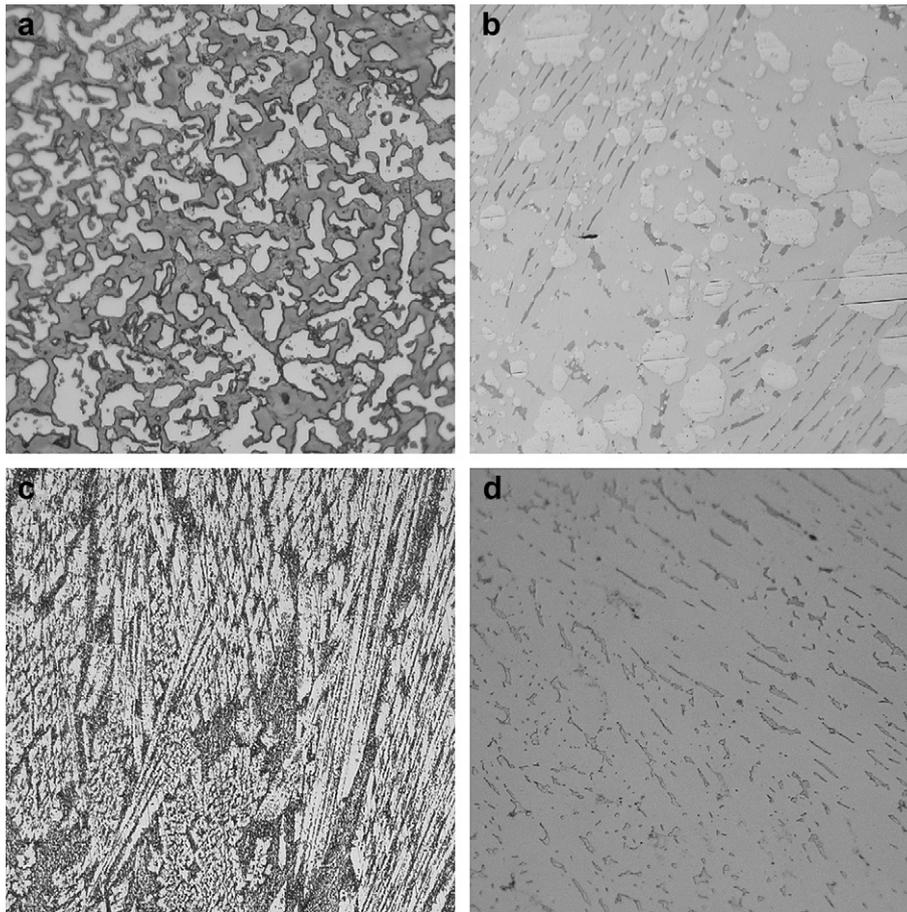


Fig. 3. Microphotographs of selected U–Cu–Al alloys: (a) $U_{25}Cu_{25}Al_{50}$ ($\times 500$), (b) $U_{33}Cu_{50}Al_{17}$ ($\times 200$), (c) $U_{17}Cu_{75}Al_{18}$ ($\times 100$) and (d) $U_8Cu_{52}Al_{40}$ ($\times 200$).

Table 2
Ternary phases from the U–Cu–Al system.

Phase	Structure type	Space group	Lattice parameters				x
			a	b	c	V	
UCu _{4+x} Al _{8-x} (τ ₁)	ThMn ₁₂	I4/mmm	8.7938(2)	–	5.1232(1)	396.18(2)	0
			8.7402(2)	–	5.1038(1)	389.89(2)	1
			8.7096(4)	–	5.0664(2)	384.33(3)	2
UCu _{6+x} Al _{5-x} (τ ₂)	TbCu _{6,4} Al _{4,6}	Fddd	14.2730(7)	14.9077(9)	6.5818(3)	1400.46(13)	0
			14.4102(11)	14.6926(10)	6.5843(5)	1394.05(18)	0.2
UCu _{6+x} Al _{5-x} (τ ₃)	BaCd ₁₁	I4 ₁ /amd	10.2822(5)	–	6.5802(4)	695.69(6)	0.38
			10.2471(4)	–	6.5883(3)	691.78(4)	0.68
U ₂ Cu _{7+x} Al _{10-x} (τ ₄)	Th ₂ Zn ₁₇	R $\bar{3}m$	8.8227(5)	–	12.8817(8)	868.38(9)	0.6
			8.8118(2)	–	12.8706(4)	865.49(4)	1
			8.7866(2)	–	12.8263(4)	857.58(4)	2
			8.7426(3)	–	12.7712(6)	845.36(6)	3
			8.7195(4)	–	12.7542(7)	839.78(7)	4
			8.7055(5)	–	12.6926(8)	833.05(9)	5
UCu _{5+x} Al _{1-x} (τ ₅)	YbMo ₂ Al ₄	I4/mmm	6.4136(4)	–	4.9506(4)	203.64(2)	0
			6.4044(3)	–	4.9294(3)	202.19(2)	0.18
UCu _{3+x} Al _{2-x} (τ ₆)	CaCu ₅	P6/mmm	5.1363(4)	–	4.1614(3)	95.07(1)	0
			5.1070(1)	–	4.1619(1)	94.01(1)	0.3
			5.0979(2)	–	4.1605(2)	93.64(1)	0.5

4. Results and discussion

4.1. The U–Cu–Al system

The isothermal section at 600 °C of the U–Cu–Al phase diagram in concentration region of 0–45/75 at.% Al is presented in Fig. 1. X-ray diffraction patterns and microstructures of selected U–Cu–Al annealed alloys are illustrated in Figs. 2 and 3, respectively.

The uranium-based binary UAl₃ (AuCu₃-type), UAl₂ (MgCu₂-type) and UCu₅ (AuBe₅-type) compounds were usually detected in the Al- or Cu-rich region of the U–Cu–Al system. Moreover, the binary UAl₂ compound was found to dissolve ~12 at.% Cu. According to the Cu–Al phase diagram, the Cu_{1-x}Al_x (Cu-rich solid solution) (Cu-type), ht–Cu_{0,75}Al_{0,25} (W-type), rt–Cu₉Al₄ (own-type), rt–Cu₃₃Al₁₇ (own-type), ht–Cu_{1,5}Al (Ni₂In-type) and ht–CuAl (own-type) phases are stable at 600 °C. Some of them

were observed in annealed ternary alloys from the Cu-rich region. Questionable equilibrium lines from this region are presented by broken lines.

The existence of the four early reported ternary UCu_{4+x}Al_{8-x} ($x \sim 0-2$) (ThMn₁₂-type) (τ₁), U₂Cu_{7+x}Al_{10-x} ($x \sim 0.6-5$) (Th₂Zn₁₇-type) (τ₄), UCu₅Al (YbMo₂Al₄-type) (τ₅) and UCu_{3+x}Al_{2-x} ($x \sim 0-0.5$) (CaCu₅-type) (τ₆) phases has been confirmed by the present work and their homogeneity ranges were verified on a basis of X-ray diffraction data. Calculated lattice parameters of above mentioned phases are given in Table 2. It should be also noted that the UCu₅Al compound was observed to have a small homogeneity range, dissolving ~2 at.% Cu(Al), and that the previous reported co-existence of two phases with the same CaCu₅-type in the annealed at 600 °C UCu_{3+x}Al_{2-x} alloys with $x \sim 0.3$ [32] was not detected.

Formation of the early reported UCuAl₂ (TiAl₃-type) U₂Cu₃Al (MgZn₂-type) and U₂Cu₉Al (MgZn₂-type) intermetallic compounds were not confirmed at 600 °C. It is supposed that these ternaries can exist at other temperatures or stabilize by impurities. Corresponded annealed samples were not single phase and contained other phases (U₂₅Cu₂₅Al₅₀ (τ₄, τ₆, and solid solution based on UAl₂); U₃₃Cu₅₀Al₁₇ (τ₅, τ₆, and α-U); U₁₇Cu₇₅Al₈ (τ₅ and UCu₅) (Fig. 3a–c).

In the annealed alloys with composition along the cross-section with 8.3 at.% uranium two new ternary UCu_{6+x}Al_{5-x} phases with $x \sim 0-0.2$ (τ₂) and $x \sim 0.38-0.68$ (τ₃) were found. On the basis of primary analysis of the X-ray diffraction data the orthorhombic TbCu_{6,4}Al_{4,6} and tetragonal BaCd₁₁ structure types were assigned for the above sited phases. Lattice parameters are presented in Table 2. Synthesis of the single phase samples, accurate crystal structure determination, magnetic and transport properties of these phases will be published in a further paper.

4.2. The U–Cu–Ga system

Based on X-ray phase and microstructure analysis the isothermal section of the U–Cu–Ga system at 600 °C was constructed in the 0–40/75 at.% Ga concentration range and is presented in Fig. 4. X-ray diffraction patterns and microstructures of some U–Cu–Ga annealed alloys are shown in Figs. 5 and 6, respectively.

The formation of the binary UGa₃ (AuCu₃-type), UGa₂ (AlB₂-type), U₃Ga₅ (Pu₃Pd₅-type) and UCu₅ (AuBe₅-type) compounds were confirmed to exist at 600 °C. The previously reported solubility of copper in UGa₂ was also confirmed: UGa₂ dissolves up to

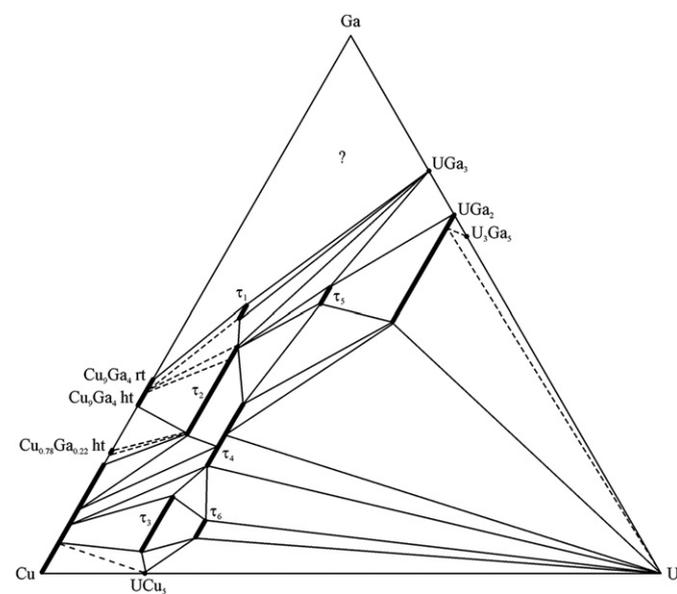


Fig. 4. Isothermal section of the U–Cu–Ga system at 600 °C. Ternary phases: (τ₁) U_{2-x}(Cu_{7+x}Ga_{10-x})_{1+δ} ($\epsilon \sim 0.5$, $\delta \sim 0.03$, $0.5 \leq x \leq 1$); (τ₂) U₂Cu_{7+x}Ga_{10-x} ($2 \leq x \leq 5$); (τ₃) UCu_{5+x}Ga_{1-x} ($0 \leq x \leq 0.7$); (τ₄) UCu_{3+x}Ga_{2-x} ($0 \leq x \leq 0.8$); (τ₅) UCu_{1+x}Ga_{3-x} ($0.35 \leq x \leq 0.5$); (τ₆) U₁₄Cu_{44+x}Ga_{7-x} ($0.5 \leq x \leq 2.5$).

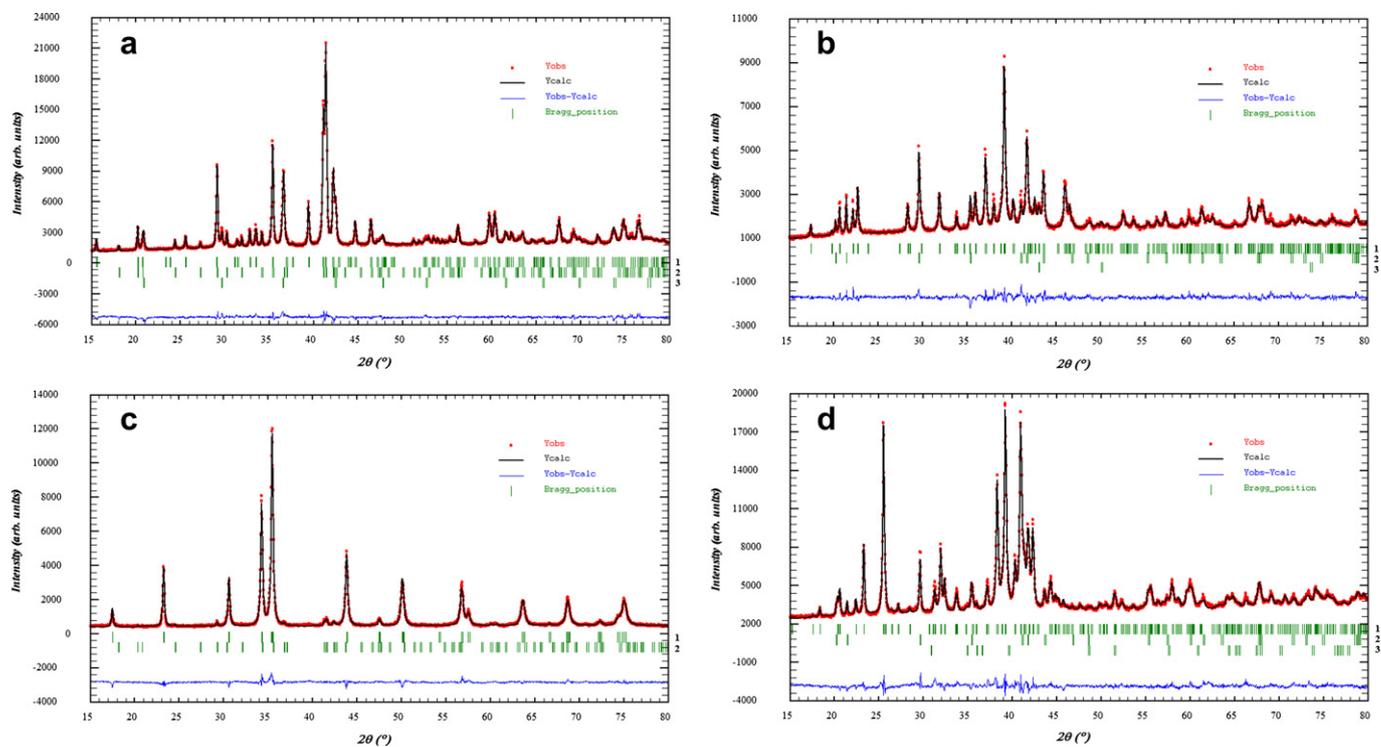


Fig. 5. X-ray diffraction patterns of selected U–Cu–Ga alloys: (a) $U_{10}Cu_{42}Ga_{48}$ (1 – τ_1 , 2 – τ_2 , 3 – UGa_3); (b) $U_{14}Cu_{71}Ga_{15}$ (1 – τ_3 , 2 – τ_4 , 3 – Cu); (c) $U_{20}Cu_{30}Ga_{50}$ (1 – τ_5 , 2 – τ_2); (d) $U_{22}Cu_{67}Ga_{11}$ (1 – τ_6 , 2 – τ_4 , 3 – α -U).

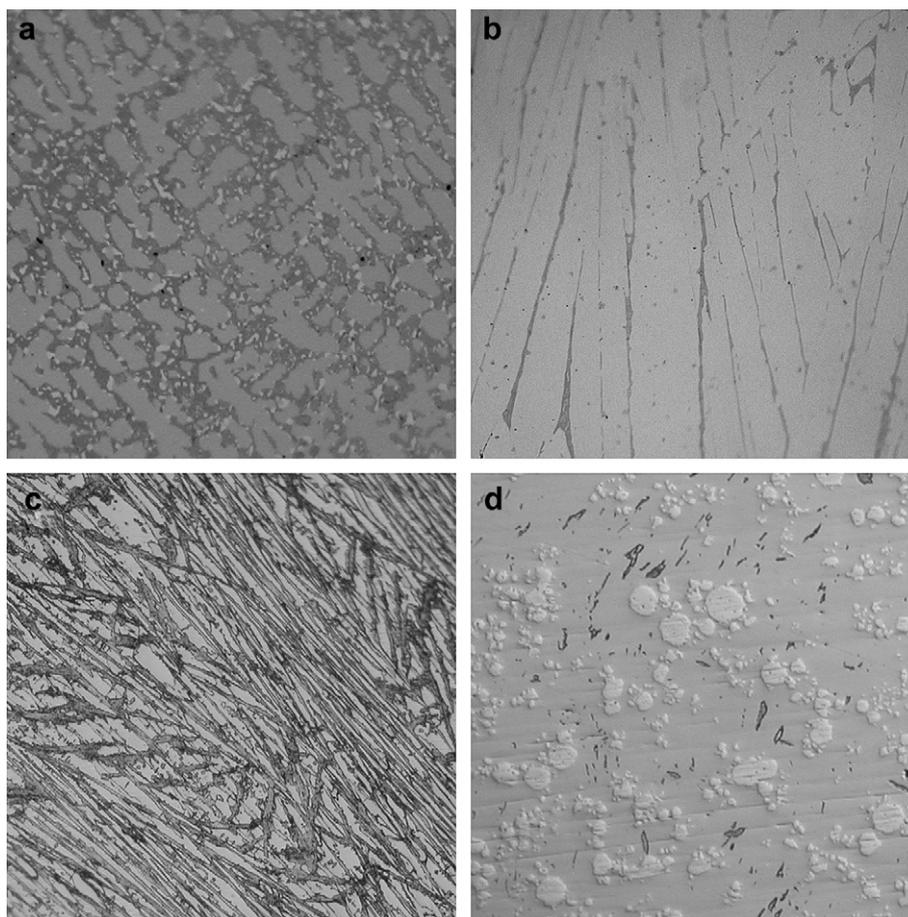


Fig. 6. Microphotographs of selected U–Cu–Ga alloys: (a) $U_{33}Cu_{33}Ga_{34}$ ($\times 500$), (b) $U_{20}Cu_{30}Ga_{50}$ ($\times 200$), (c) $U_{17}Cu_{76}Ga_7$ ($\times 100$) and (d) $U_{30}Cu_{63}Ga_7$ ($\times 100$).

Table 3
Ternary phases from the U–Cu–Ga system.

Phase	Structure type	Space group	Lattice parameters				x
			a	b	c	V	
U _{2-ε} (Cu _{7+x} Ga _{10-x}) _{1+δ} (τ ₁)	Related to Th ₂ Ni ₁₇	P6 ₃ /mmc	8.8083(2)	–	8.5835(2)	576.74(2)	0.5
			8.7975(3)	–	8.5745(3)	574.72(3)	1
U ₂ Cu _{7+x} Ga _{10-x} (τ ₂)	Th ₂ Zn ₁₇	R $\bar{3}m$	8.7645(4)	–	12.8134(7)	852.41(7)	2
			8.7276(2)	–	12.7897(3)	843.68(3)	3
			8.7005(3)	–	12.7600(5)	836.50(6)	4
			8.6871(5)	–	12.6710(8)	828.11(9)	5
			8.0253(6)	4.9983(3)	10.1752(7)	408.16(5)	0
UCu _{5+x} Ga _{1-x} (τ ₃)	CeCu ₆	Pnma	8.0187(7)	4.9994(4)	10.1417(9)	406.57(6)	0.3
			8.0172(3)	5.0016(2)	10.1018(4)	405.07(3)	0.5
			8.0172(8)	5.0060(4)	10.0746(9)	404.34(6)	0.7
			5.1434(4)	–	4.1300(3)	94.62(1)	0
			5.1162(2)	–	4.1445(1)	93.95(1)	0.25
UCu _{3+x} Ga _{2-x} (τ ₄)	CaCu ₅	P6/mmm	5.0887(4)	–	4.1511(3)	93.09(1)	0.5
			5.0787(3)	–	4.1527(2)	92.76(1)	0.75
			4.1512(2)	–	10.0278(5)	172.80(1)	0.35
			4.1300(1)	–	10.1430(4)	173.01(1)	0.5
			11.6625(5)	–	8.6248(4)	1015.93(8)	0.5
U ₁₄ Cu _{44+x} Ga _{7-x} (τ ₆)	Related to Gd ₁₄ Ag ₅₁	P6/m	11.6528(6)	–	8.6212(5)	1013.82(9)	2.5

20 at.% Cu in the annealed alloys. The Cu_{1-x}Ga_x solid solution (Cu-type) and intermediate phases, ht–Cu_{0.78}Ga_{0.22} (Mg-type), ht–Cu₉Ga₄ (Cu₉Al₄-type) and rt–Cu₉Ga₄ (unknown type) are usually observed at the investigated temperature.

In the U–Cu–Ga system was confirmed the existence of the three early reported ternary phases and their homogeneity ranges at 600 °C: U₂Cu_{7+x}Ga_{10-x} (x ~ 2–5) (Th₂Zn₁₇-type) (τ₂), UCu_{3+x}Ga_{2-x} (x ~ 0–0.8) (CaCu₅-type) (τ₄) and UCu_{1+x}Ga_{3-x} (x ~ 0.35–0.5) (BaAl₄-type) (τ₅) (Table 3). The reported ternary gallides, U₂CuGa₃ (Lu₂CoGa₃-type) and UCuGa (LiGaGe-type), were not observed in the annealed U–Cu–

Ga alloys. Herein, the U₂CuGa₃ (or UCu_{0.5}Ga_{1.5} = U₃₃Cu₁₇Ga₅₀) is a part of solid solution based on the binary UGa₂ compound. Annealed UCuGa (=U₃₃Cu₃₃Ga₃₄) alloy contains three phases (τ₄, solid solution based on UGa₂ and α-U) (Fig. 6a).

During the X-ray phase analysis of the as-cast and annealed alloys with composition closed to U₁₀Cu₄₀Ga₅₀ a new ternary gallide (τ₁), with small homogeneity range, was found. Its crystal structure was solved from powder X-ray counter data of multiphase samples. Characteristic intensities of the peaks and indexing by a hexagonal unit cell with lattice parameters a ~ 8.80 Å and c ~ 8.58 Å indicated the Th₂Ni₁₇ structure type (space group P6₃/mmc). Rietveld method was applied for testing this model. However, the best results were obtained for the case of a defected model, where all atoms occupy the same sites as in the Th₂Ni₁₇ type with the exception of the 2b position, which is partially split into 4e site. Thus, the final composition of this phase was found to be U_{2-ε}(Cu_{7+x}Ga_{10-x})_{1+δ}, with ε ~ 0.5, δ ~ 0.03 and x ~ 0.5–1 and its lattice parameters can be found in Table 3. Nevertheless, synthesis and accurate characterization of single crystals are urgently needed.

In the as-prepared as well as in the annealed samples from the Cu-rich corner we found two new ternary phases and their crystal structures were studied on a basis of powder and single crystal X-ray diffraction data. Compositions and homogeneity ranges of these phases were established as UCu_{5+x}Ga_{1-x} (x ~ 0–0.7) (τ₃) and U₁₄Cu_{44+x}Ga_{7-x} (x ~ 0.5–2.5) (τ₆). Ternary gallides are derived from the CeCu₆ and Gd₁₄Ag₅₁ structure types. Calculated lattice parameters of selected alloys are shown in Table 3.

4.3. The UCu_{5+x}Ga_{1-x} phase

The crystal structure of the UCu_{5+x}Ga_{1-x} phase was first refined by the Rietveld method on the basis of powder X-ray diffraction

Table 4
Crystal data and structure refinement for UCu_{5.5}Ga_{0.5}.

Empirical formula	UCu _{5.5} Ga _{0.5}
Structure type	CeCu ₆
Crystal system	Orthorhombic
Space group	Pnma
Pearson symbol	oP28
Cell parameters	
a	7.997(2) Å
b	4.9871(12) Å
c	10.115(4) Å
V	403.4(2) Å ³
Formula units per cell	4
Calculated density	10.248 g/cm ³
Crystal shape and colour	Irregular, silvery
Diffractometer	Enraf–Nonius Mach III
Wavelength	Mo-K _α (λ = 0.71073 Å)
Monochromator	Graphite
Temperature	293(2) K
Absorption coefficient	71.487 mm ⁻¹
F(000)	1068
θ range for data collection	3.25°–41.04°
Scan type	ω–2θ
Range in hkl	±8, ±5, ±12
Total no. reflections	4182
Independent reflection	630
Reflections with I > 2σ(I)	406
Structure refinement	SHELXL-97 (Sheldrick-1997)
Refinement method	Full-matrix least-squares on F ²
Data/restraints/parameters	630/0/41
Goodness-of-fit on F	1.005
Final R indices R1, wR2 ^a	0.0568, 0.0978
Weighting scheme a, b ^b	0.0104, 0
Extinction coefficient	0.0016(3)
Largest diff. peak/hole	4.438/–3.849 e/Å ³

^a R1 = ∑(|F_o – F_c|)/∑|F_o|, 5σwR2 = {∑ w[(F_o² – F_c²)²]/∑ w[(F_o²)²]}^{1/2};

^b w = 1/[σ²(F_o²) + (aP)² + bP], in which P = [(F_o² + 2F_c²)/3].

Table 5
Atom coordinates and isotropic displacement parameters for UCu_{5.5}Ga_{0.5}.

Atom	Site	x	y	z	U _{eq} (Å ²)	Occupation
U	4c	0.25799(15)	¼	0.56181(9)	0.0129(3)	1
M1	4c	0.4049(5)	¼	0.0165(3)	0.0132(7)	1
M2	4c	0.3186(4)	¼	0.2547(3)	0.0113(7)	1
M3	4c	0.1432(4)	¼	0.8570(3)	0.0118(7)	1
M4	4c	0.0632(5)	¼	0.0926(3)	0.0140(7)	1
M5	8d	0.0659(3)	0.5053(4)	0.3082(2)	0.0103(5)	1

M = 0.92Cu + 0.08Ga.

Table 6
Anisotropic displacement parameters for $\text{UCu}_{5.5}\text{Ga}_{0.5}$.

Atom	U11	U22	U33	U23	U13	U12
U	0.0072(6)	0.0165(5)	0.0148(5)	0	−0.0005(4)	0
M1	0.011(2)	0.0189(17)	0.0091(14)	0	−0.0007(12)	0
M2	0.0035(17)	0.0193(17)	0.0112(14)	0	0.0037(12)	0
M3	0.0066(19)	0.0234(17)	0.0054(13)	0	−0.0006(10)	0
M4	0.010(2)	0.0207(18)	0.0110(15)	0	−0.0002(13)	0
M5	0.0081(14)	0.0146(12)	0.0082(10)	−0.0011(7)	−0.0006(10)	−0.0003(8)

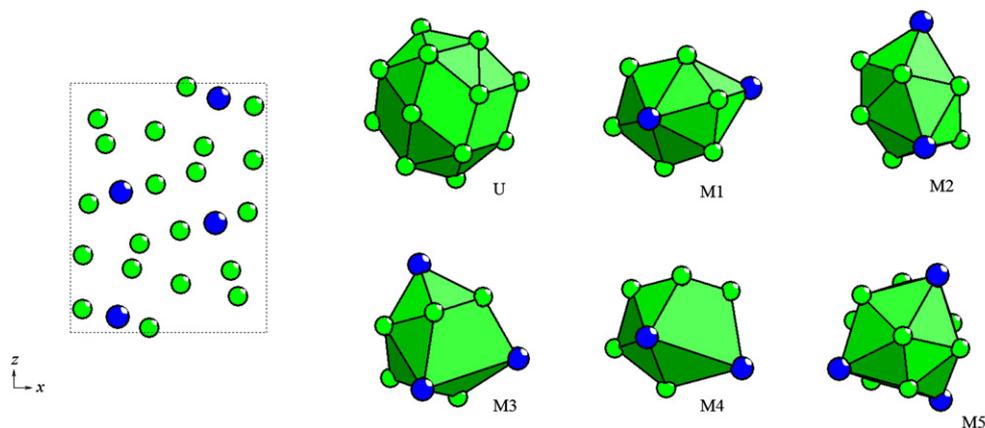


Fig. 7. Projection of the unit cell of the structure of $\text{UCu}_{5+x}\text{Ga}_{1-x}$ on the xz plane and coordination polyhedra of the atoms: U (big circles) and M (Cu and Ga) (small circles).

data. Starting positional parameters of the atoms were taken from the CeCu_6 structure type. Further studies were made on an irregular-shape single crystal extracted from the $\text{U}_{14.3}\text{Cu}_{78.7}\text{Ga}_7$ ($=\text{UCu}_{5.5}\text{Ga}_{0.5}$) alloy. Details of the data collection and structure refinement for $\text{UCu}_{5.5}\text{Ga}_{0.5}$ are given in Table 4. The refined values of the atomic coordinates and thermal displacement parameters are presented in Tables 5 and 6. All the crystallographic positions are fully occupied. Statistical mixtures of Cu and Ga were fixed during the refinement, as they are not distinguishable by X-ray diffraction.

The projection of the unit cell on the xz plane and coordination polyhedra of the atoms of the $\text{UCu}_{5+x}\text{Ga}_{1-x}$ structure are shown in Fig. 7. The neighbours of the U atoms form 19-vertex polyhedra, $[\text{M}_1\text{M}_2\text{M}_3\text{M}_4\text{M}_5\text{U}]$. The M1, M2, M3 and M5 atoms are

Table 7
Interatomic distances (d , Å) and coordination numbers (CN) for atoms in the structures of $\text{UCu}_{5.5}\text{Ga}_{0.5}$.

Atoms	d	CN	Atoms	d	CN
U –		19	M3 –		12
– 2M1	2.850(2)		– 1M4	2.467(4)	
– 2M4	2.891(2)		– 1M1	2.642(5)	
– 1M4	2.898(4)		– 2M5	2.660(4)	
– 1M1	2.933(4)		– 2M5	2.673(4)	
– 2M5	3.112(2)		– 2M2	2.717(2)	
– 1M3	3.124(3)		– 1U	3.124(3)	
– 1M2	3.144(3)		– 1U	3.188(3)	
– 2M5	3.151(3)		– 2U	3.337(2)	
– 1M3	3.188(3)				
– 2M2	3.225(2)		M4 –		9
– 2M5	3.250(2)		– 1M3	2.467(4)	
– 2M3	3.337(2)		– 1M2	2.492(5)	
			– 2M5	2.525(3)	
M1 –		12	– 1M2	2.619(5)	
– 2M5	2.446(3)		– 1M1	2.839(6)	
– 1M2	2.506(4)		– 2U	2.891(2)	
– 2M5	2.534(4)		– 1U	2.898(4)	
– 1M3	2.642(5)				
– 1M4	2.839(6)		M5 –		12
– 2U	2.850(2)		– 1M2	2.437(4)	
– 1U	2.933(4)		– 1M5	2.441(3)	
– 2M1	2.940(3)		– 1M1	2.446(3)	
			– 1M2	2.449(4)	
M2 –		12	– 1M4	2.525(3)	
– 2M5	2.437(4)		– 1M1	2.534(4)	
– 2M5	2.449(4)		– 1M5	2.546(3)	
– 1M4	2.492(5)		– 1M3	2.660(4)	
– 1M1	2.506(4)		– 1M3	2.673(4)	
– 1M4	2.619(5)		– 1U	3.112(2)	
– 2M3	2.717(2)		– 1U	3.151(3)	
– 1U	3.144(3)		– 1U	3.250(2)	
– 2U	3.225(2)				

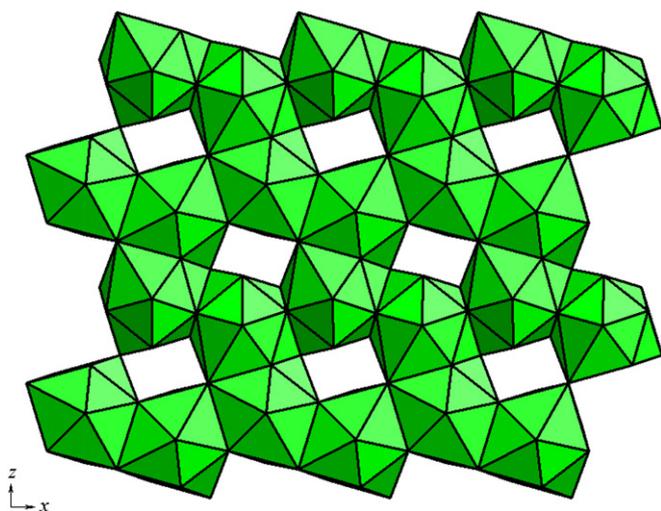


Fig. 8. Packing of icosahedrons in the structure of $\text{UCu}_{5+x}\text{Ga}_{1-x}$.

Table 8
Crystal data and structure refinement for U₁₄Cu₄₆Ga₅.

Empirical formula	U ₁₄ Cu ₄₆ Ga ₅
Structure type	Related to Gd ₁₄ Ag ₅₁
Crystal system	Hexagonal
Space group	<i>P6/m</i>
Pearson symbol	<i>hP68</i>
Cell parameters	
<i>a</i>	11.650(2) Å
<i>c</i>	8.6020(15) Å
<i>V</i>	1011.1(3) Å ³
Formula units per cell	1
Calculated density	10.795 g/cm ³
Crystal shape and colour	Irregular, silvery
Diffractometer	Enraf–Nonius Mach III
Wavelength	Mo-K _α (λ = 0.71073 Å)
Monochromator	Graphite
Temperature	293(2) K
Absorption coefficient	81.931 mm ⁻¹
<i>F</i> (000)	2767
θ range for data collection	2.02°–44.88°
Scan type	ω–2θ
Range in <i>hkl</i>	±13, ±13, ±10
Total no. reflections	14,390
Independent reflection	1839
Reflections with <i>I</i> > 2σ(<i>I</i>)	659
Structure refinement	SHELXL-97 (Sheldrick-1997)
Refinement method	Full-matrix least-squares on <i>F</i> ²
Data/restraints/parameters	1839/0/64
Goodness-of-fit on <i>F</i>	1.000
Final <i>R</i> indices <i>R</i> ₁ , <i>wR</i> ₂ ^a	0.0647, 0.0884
Weighting scheme <i>a</i> , <i>b</i> ^b	0.0277, 0
Extinction coefficient	0.00035(6)
Largest diff. peak/hole	3.717/–5.621 e/Å ³

$$^a R_1 = \sum (|F_o| - |F_c|) / \sum |F_o|, 5\text{emw}R_2 = \{ \sum w[(F_o^2 - F_c^2)^2] / \sum w[(F_o^2)^2] \}^{1/2};$$

$$^b w = 1/[\sigma^2(F_o^2) + (aP)^2 + bP], \text{ in which } P = [(F_o^2 + 2F_c^2)/3].$$

Table 9
Atom coordinates and isotropic displacement parameters for U₁₄Cu₄₆Ga₅.

Atom	Site	<i>x</i>	<i>y</i>	<i>z</i>	<i>U</i> _{eq/iso} (Å ²)	Occupation
U1	2e	0	0	0.3086(3)	0.0050(5)	1
U2A	6j	0.1114(6)	0.3654(12)	0	0.0065(14)	0.45(3)
U2B	6j	0.1286(5)	0.4071(9)	0	0.0067(11)	0.57(3)
U3	6k	0.47068(16)	0.13838(16)	½	0.0061(4)	1
M1	2c	1/3	2/3	0	0.028(3)	1
(M1) ^a	6j	0.330(4)	0.688(3)	0	0.004(4)	0.336(13)
M2	4h	1/3	2/3	0.2761(6)	0.0045(12)	1
M3	6j	0.0405(11)	0.1390(10)	0	0.006(3)	0.494(19)
M4	6k	0.0630(5)	0.2412(5)	½	0.0074(11)	1
M5	12l	0.4938(4)	0.1081(4)	0.1538(4)	0.0085(8)	1
M6	12l	0.2687(3)	0.0695(4)	0.2452(4)	0.0105(8)	1
M7	12l	0.1085(4)	0.4355(4)	0.3257(4)	0.0091(8)	1

M = 0.90Cu + 0.10Ga.

^a An alternatively atomic position of M1 atoms in the disordered model.

located inside deformed icosahedra (coordination number 12), [U₃M₁M₂M₃M₄M₅], [U₃M₁M₃M₂M₄M₅], [U₄M₁M₂M₄M₅] and [U₃M₁M₂M₃M₄M₅], respectively. The 9-vertex polyhedra, [U₃M₁M₂M₃M₅], are coordination spheres of the M4 atoms. The

Table 10
Anisotropic displacement parameters for U₁₄Cu₄₆Ga₅.

Atom	U11	U22	U33	U23	U13	U12
U1	0.0039(8)	0.0039(8)	0.0074(11)	0	0	0.0019(4)
U3	0.0040(8)	0.0070(8)	0.0081(6)	0	0	0.0032(7)
M1	0.040(5)	0.040(5)	0.005(5)	0	0	0.020(3)
M2	0.0019(18)	0.0019(18)	0.010(3)	0	0	0.0009(9)
M3	0.007(6)	0.002(6)	0.005(5)	0	0	–0.001(4)
M4	0.005(3)	0.004(3)	0.009(2)	0	0	–0.001(2)
M5	0.007(2)	0.008(2)	0.0090(15)	0.0013(13)	–0.0007(14)	0.0025(16)
M6	0.0037(18)	0.022(2)	0.0058(14)	0.0005(16)	0.0000(13)	0.0064(17)
M7	0.011(2)	0.0056(19)	0.0090(16)	0.0024(12)	0.0002(13)	0.0029(17)

UCu_{5+x}Ga_{1-x} structure can be composed by stacking of the icosahedra around the M5 atoms. These icosahedra are connected along the *y* axis by the vertexes with shared M5 atoms, and along the direction parallel to the *xz* plane by triangle faces (Fig. 8). From this point of view the structure can be seen as a layered one, where two types of layers (*A* and *B*) form a sequence *ABAB'* along [010] direction. *A* layer (a distorted 6³ net) is composed by M atoms, while *B* layer (3535, 3²5², 3²5³ and 3⁴5 net) and its 180° rotated analogue, *B'*, are formed by U and M atoms.

Interatomic distances (*d*) in the UCu_{5+x}Ga_{1-x} structure are presented in Table 7. These distances are in general close to the sum of the atomic radii of the respective atoms [33]. Significant shorter distances (with *d* less than 2*r*_{atomic}) can be found for M–M atoms, which are indication of strong interactions between these atoms. The minimum *d*_{M–M} was found with 2.437 Å (value of reducing Δ ~ 5%).

4.4. The U₁₄Cu_{44+x}Ga_{7-x} phase

The primary analysis of powder X-ray diffraction data of the as-cast and annealed U₁₄Cu_{44+x}Ga_{7-x} samples pointed out to the Gd₁₄Ag₅₁ structure type for the above sited phase. Investigation of an irregular-shape single crystal, isolated from crushed U_{21.5}Cu_{70.8}Ga_{7.7} (=U₁₄Cu₄₆Ga₅) sample, was conducted considering this model. Crystal data and structure refinement results are displayed in Table 8. Final atom coordinates, site occupancies and displaced parameters for the U₁₄Cu₄₆Ga₅ structure are listed in Tables 9 and 10. The present results indicated a Gd₁₄Ag₅₁-based structure type for U₁₄Cu₄₆Ga₅, with the uranium atoms in the layer at *z* = 0 splitted into two half-occupied 6j positions (U2A and U2B sites). Large displacement parameters of M1 atoms are observed in this structure, which can indicate possible atom disorder of the 2c position. Similar disorder of atoms can also be found in the structure of the Ce₁₄Cu₅₁ type (2c is splitted into 6j). However, parallel structure refinement using this last model does not give better results.

The unit cell and coordination polyhedra of the atoms are presented in Fig. 9. The number of the neighbours for uranium atoms varies from 13 to 16. Coordination spheres can be presented as [U₁M₃M₄M₆M₆] (CN = 16), [M₁M₅M₆M₄M₇] (CN = 13), [M₁M₃M₁M₅M₆M₄M₇] (CN = 14), [M₂M₄M₂M₅M₆M₇] (CN = 14) for U1, U2A, U2B and U3 atoms, and they have similar details with 14-vertex Frank–Kasper polyhedron. The M1 atoms are located inside full-capped trigonal prisms [U₂B₃M₂M₅] (CN = 11). Four-capped deformed trigonal prisms, [U₃M₁M₅M₇] (CN = 10), are polyhedra for the M2 atoms. Polyhedra (deformed full capped trigonal prisms) of the M3 atoms consist of eleven neighbouring atoms [U₁U₂A₂U₂B₁M₃M₆]. The M4 and M6 atoms are coordinated by distorted icosahedra (CN = 12), [U₁U₃M₄M₆M₇] and [U₁U₂A₂U₃M₃M₄M₅M₆M₇], respectively. 11- and 10-vertex polyhedra (somewhat like a defected icosahedra), [U₂B₃U₃M₁M₂M₅M₆M₇] and [U₂B₁U₃M₂M₄M₅M₆], are the coordination spheres for M5 and M7 atoms, respectively.

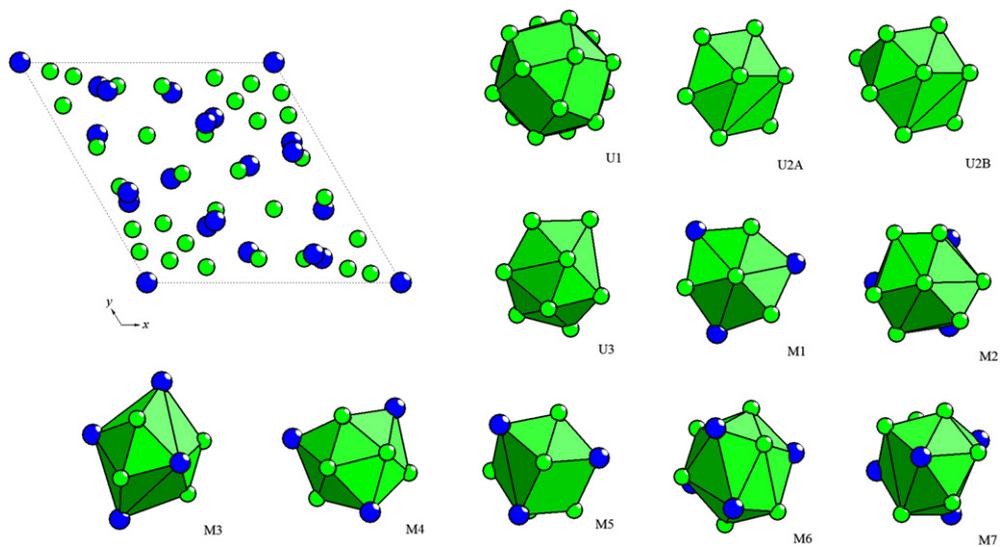


Fig. 9. Projection of the unit cell of the structure of $U_{14}Cu_{44+x}Ga_{7-x}$ on the xy plane and coordination polyhedra of the atoms: U (big circles) and M (Cu and Ga) (small circles).

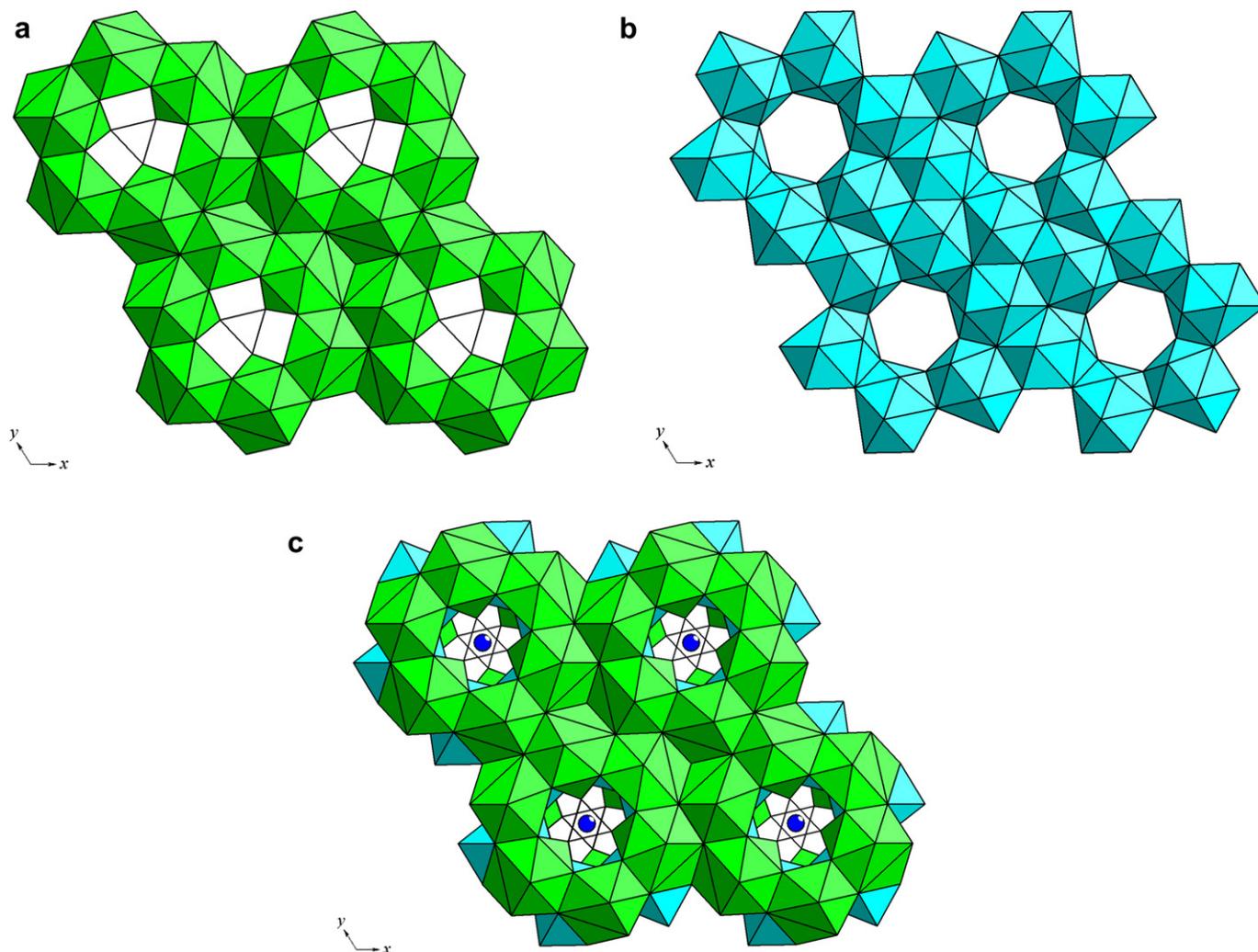


Fig. 10. An aggregation of the hexagonal like wheel composed by the coordination polyhedra of the U2A, U2B (a) and U3 (b) atoms, and their packing (c) in the structure of $U_{14}Cu_{44+x}Ga_{7-x}$.

Table 11
Interatomic distances and coordination polyhedra of the atoms in the structures of $U_{14}Cu_{46}Ga_5$.

Atoms	<i>d</i>	CN	Atoms	<i>d</i>	CN
U1 –		16	M4 –		12
– 6M6	2.867(3)		– 2M4	2.524(5)	
– 6M4	3.014(4)		– 2M7	2.540(6)	
– 3M3	3.021(5)		– 2M6	2.583(5)	
– 1U1	3.293(4)		– 2M6	2.630(4)	
U2A –		13	– 1U3	2.933(4)	
– 2M6	2.814(10)		– 2U1	3.014(5)	
– 2M7	2.923(6)		– 1U3	3.020(7)	
– 2M6	2.926(6)		M5 –		11
– 2M5	2.992(10)		– 1M6	2.553(6)	
– 2M5	3.069(6)		– 1M7	2.556(5)	
– 1M1	3.151(10)		– 1M5	2.594(7)	
– 2M5	3.205(13)		– 1M2	2.601(4)	
U2B –		14	– 1M5	2.646(5)	
– 1M3	2.757(15)		– 1M1	2.722(3)	
– 1M1	2.760(7)		– 1M7	2.725(5)	
– 2M7	2.844(4)		– 1U2B	2.865(7)	
– 2M5	2.865(10)		– 1U2B	2.952(10)	
– 2M5	2.952(6)		– 1U2B	2.955(5)	
– 2M5	2.954(8)		– 1U3	3.027(4)	
– 2M6	3.009(8)		M6 –		12
– 2M6	3.170(5)		– 1M5	2.553(6)	
U3 –		14	– 1M7	2.579(7)	
– 2M7	2.854(4)		– 1M4	2.583(4)	
– 2M7	2.917(4)		– 1M4	2.630(5)	
– 1M4	2.933(6)		– 1M3	2.712(8)	
– 2M7	2.957(4)		– 1M7	2.725(4)	
– 2M2	2.982(3)		– 2M6	2.814(4)	
– 2M6	3.016(4)		– 1U2A	2.814(5)	
– 1M4	3.020(2)		– 1U1	2.867(4)	
– 2M5	3.027(4)		– 1U2A	2.926(7)	
			– 1U3	3.016(4)	
M1 –		11	M7 –		10
– 2M2	2.375(5)		– 1M4	2.540(6)	
– 6M5	2.722(3)		– 1M5	2.556(5)	
– 3U2B	2.760(7)		– 1M6	2.579(4)	
			– 1M2	2.691(3)	
M2 –		10	– 1M5	2.725(6)	
– 1M1	2.375(5)		– 1M6	2.725(7)	
– 3M5	2.601(4)		– 1U2B	2.844(4)	
– 3M7	2.691(3)		– 1U3	2.854(5)	
– 3U3	2.982(3)		– 1U3	2.917(4)	
			– 1U3	2.957(5)	
M3 –		11			
– 2M3	2.499(9)				
– 2M6	2.712(6)				
– 2M6	2.735(10)				
– 1U2B	2.757(15)				
– 2U1	3.021(6)				
– 1U2A	3.282(16)				
– 1U2A	3.324(18)				

The structure of $U_{14}Cu_{44+x}Ga_{7-x}$ can be seen as a packing of two different types of layers (slabs) along the *z* direction. These layers are the aggregation of the six-membered wheel, which are composed by the coordination polyhedra of the U2A, U2B and U3 atoms (Fig. 10a and b). The hexagonal cavities, which are located in the centres of these wheels, are filled by the U1 atoms (Fig. 10c).

Interatomic distances in the $U_{14}Cu_{44+x}Ga_{7-x}$ are close to the sum of the atomic radii in the pure metals [33] and are listed in Table 11. The shortest bonds for U–M atoms are equal to 2.757 Å ($\Delta \sim 2\%$) and those for the M–M atoms amount to 2.375 Å ($\Delta \sim 7\%$).

5. Conclusion

Isothermal sections of the phase diagram of the U–Cu–Al and U–Cu–Ga systems have been constructed at 600 °C by means of

X-ray diffraction, optical microscopy and scanning electronic microscopy. The interaction of the components in these systems leads to the formation of twelve ternary phases (five of them reported here for the first time): $UCu_{4+x}Al_{8-x}$ ($x \sim 0-2$), $UCu_{6+x}Al_{5-x}$ ($x \sim 0-0.2$), $UCu_{6+x}Al_{5-x}$ ($x \sim 0.38-0.68$), $U_2Cu_{7+x}Al_{10-x}$ ($x \sim 0.6-5$), $UCu_{5+x}Al_{1-x}$ ($x \sim 0-0.18$), $UCu_{3+x}Al_{2-x}$ ($x \sim 0-0.5$) and $U_{2-\epsilon}(Cu_{7+x}Ga_{10-x})_{1+\delta}$ ($\epsilon \sim 0.5$, $\delta \sim 0.03$, $x \sim 0.5-1$), $U_2Cu_{7+x}Ga_{10-x}$ ($x \sim 2-5$), $UCu_{5+x}Ga_{1-x}$ ($x \sim 0-0.7$), $UCu_{3+x}Ga_{2-x}$ ($x \sim 0-0.8$), $UCu_{1+x}Ga_{3-x}$ ($x \sim 0.35-0.5$), $U_{14}Cu_{44+x}Ga_{7-x}$ ($x \sim 0.5-2.5$), respectively. All these compounds are formed in the region with less than 33.3 at.% U. Binary UAl_2 and UGa_2 compounds form solid solutions by the Cu/Al or Cu/Ga substitutions. The available data on the U–Cu–Al and U–Cu–Ga systems point to the possibility of identification of new ternary phases in the yet unexplored systems with actinides.

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Appendix A. Supplementary data

Supplementary data related to this article can be found at <http://dx.doi.org/10.1016/j.intermet.2012.09.024>.

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